

## 204% enhanced efficiency of ZrO<sub>2</sub> nanofibers doped dye-sensitized solar cells

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Zirconia (ZrO<sub>2</sub>) nanofibers added mesoporous titania (TiO<sub>2</sub>) photoelectrode has been synthesized for dye-sensitized solar cells to enhance the efficiency of cell. The ZrO<sub>2</sub> nanofibers had reduced the resistance of the photoelectrode as well as enhancement of the absorption spectra in the ultraviolet (UV), visible, and near infrared (IR) region. The internal resistance of the photoelectrode is one of the important factor to affects the power conversion efficiency directly. The ZrO<sub>2</sub> nanofibers provide the more photon harvest and optimal electron pathway. Finally, about 200% increases in conversion efficiency has been achieved. © 2010 American Institute of Physics. [doi:10.1063/1.3459958]

Developing materials and fabrication process of dye-sensitized solar cells (DSSCs) have been challenging and has great interest to provide an alternative to conventional silicon solar cells for sustainable energy. A typical DSSC is inexpensive, semitransparent and flexible,<sup>1,2</sup> and which is an assembly of sensitized dye, a dye-immobilized nanocrystalline photoelectrode as a dye absorber, an electrolyte, and counter electrode.<sup>3</sup>

Performance of DSSC depends on several factors, such as the band gap of TiO<sub>2</sub>, particle size, surface morphology, porosity, thickness of the photoelectrode, etc.<sup>1,2</sup> Improvement of absorption of the solar spectrum has been investigated mainly by adding different types of dopants such as transition metal elements, nonmetal element; nitrogen, sulfur, boron, carbon nanotubes, and etc.<sup>4-14</sup> Metal oxides (ZnO<sub>2</sub>, SiO<sub>2</sub>, La<sub>2</sub>O<sub>3</sub>, and etc.) have also been introduced to improve the thermal stability and photocatalytic effect.<sup>15,16</sup>

ZrO<sub>2</sub> has unique properties; a high refractive index, wide optical band gap, low absorption and dispersion in the visible and near infrared spectral regions.<sup>17-20</sup> In the past, the addition of ZrO<sub>2</sub> to TiO<sub>2</sub> was reported to improve the stability of the phase, surface area, and finally the photocatalytic effects.<sup>21-23</sup> Jing *et al.* reported that ZrO<sub>2</sub> nanofibers (diameter ≈ 200 nm) have been synthesized by sol-gel process, calcinations of the zirconium oxide/poly(vinyl pyrrolidone) (PVP) composite nanofibers and electrospinning technique.<sup>24</sup> The specific surface area is 30 m<sup>2</sup>/g and crystal phase is monoclinic.

In this paper, we have reported interface and/or internal resistance of the ZrO<sub>2</sub> doped cells by examining the alternating current (ac) impedance, conductivity and resistances, and photocurrent-voltage curves.<sup>25</sup>

The photoelectrode was fabricated using precleaned fluorine-doped tin dioxide (FTO, Pilkington Conducting Glass TEC8, ~9 Ω/cm<sup>2</sup>) by squeeze printing. The TiO<sub>2</sub> paste was prepared by mixing TiO<sub>2</sub> (Degussa, P-90) with

polyethylene glycol, acetyl acetone, H<sub>2</sub>O, triton X-100, HNO<sub>3</sub>, and ZrO<sub>2</sub> nanofibers. The concentration of the ZrO<sub>2</sub>: 0, 3, 5, 7, and 9 wt % were the ratio of the mixed TiO<sub>2</sub> paste and ZrO<sub>2</sub>. The mixed solution was stirred well for 30 min. The coated photoelectrode was treated to 450 °C for 30 min at a heating rate of 5 °C/min.

The obtained TiO<sub>2</sub> film was immersed in 0.5 mmol ethanol solution of [bis(isothio-cyanato)bis(2,2'-bipyridyl-4,4'-dicarboxylato)-ruthenium(II)-bis-tetrabutyl ammonium] (N719 dye, Solaronix) for 24 h and dried in a vacuum oven. The thickness of the printed TiO<sub>2</sub> film was 10 μm, and the active area of the photoelectrode was 0.5 × 0.5 cm<sup>2</sup>. On the other hand, the counter electrode was prepared to the similar process of the fabrication for photoelectrode. Pt-Sol (Solaronix, Pt catalyst/SP) coated onto the FTO glass using a squeeze printing method. The coated paste was heat treated at 450 °C for 30 min at a heating rate of 5 °C/min. The sheet resistance of the substrate and platinized counter electrode were measured by using the four-dot method (Chang Min Co.).

The electrolyte solution consist of 0.3 M 1,2-dimethyl-3-propylimidazolium iodide, 0.5 M LiI, 0.05 M I<sub>2</sub>, and 0.5 M 4-t-butylpyridine in 3-methoxypropionitile. The ac impedance spectra were measured by the symmetric thin-layer cells. The photocurrent-voltage performances of the cell were measured using a solar simulator under the illumination of a Xe lamp (100 mW cm<sup>-2</sup>) on the 0.25 cm<sup>2</sup> active area.

Figure 1 shows the UV-vis-IR absorption spectra of the N719 dye, undoped and 7 wt % of ZrO<sub>2</sub> nanofibers doped photoelectrode. The absorption spectra show much enhanced redshift which indicates that the more photon energy could be harvest. The effective spectrum ranges from 370 to 1000 nm. This spectrum covers UV-visible-IR region. The effect of ZrO<sub>2</sub> nanofibers doped system is similar to that of tandem cell structure. The atomic force microscope (AFM) images of the pristine and 7 wt % of ZrO<sub>2</sub> nanofiber added photoelectrode are also shown the inlet of the Fig. 1. Based on the AFM, the scan area was 1.0 × 1.0 μm<sup>2</sup>, the gain size mean of TiO<sub>2</sub> surface is estimated to be around 25 nm.

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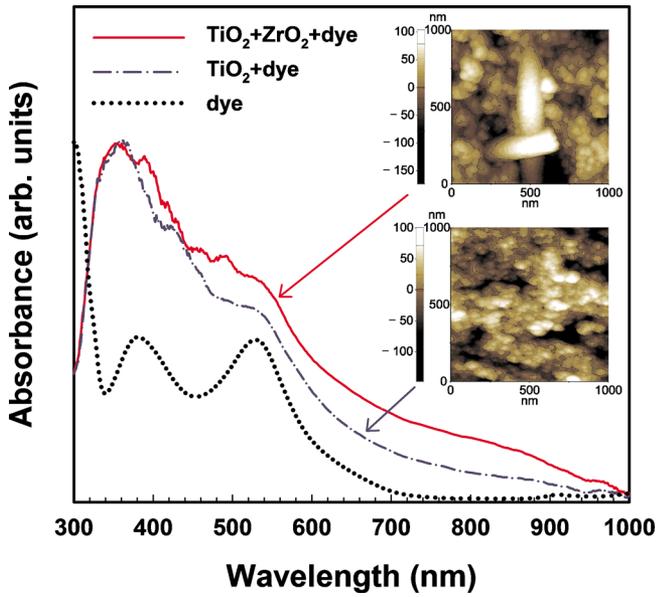


FIG. 1. (Color online) UV-vis-IR absorption spectra of N719 dye (dotted line), TiO<sub>2</sub>+N719 dye (dashed line) and TiO<sub>2</sub>+ZrO<sub>2</sub>+N719 dye (solid line), and AFM images of the ZrO<sub>2</sub> nanofiber-doped and undoped dye-sensitized solar cells.

Figure 2 shows electrochemical impedance spectroscopy (EIS) measurements for 5, 7, and 9 wt % of the ZrO<sub>2</sub> nanofiber-doped photoelectrode. In these observations, the Nyquist plots of the impedance characteristics were obtained from the dependence of the real axis resistance ( $Z'$  or  $Z_{re}$ ) and imaginary axis resistance ( $Z''$  or  $Z_{im}$ ) along with the angular frequency. The diameter of the semicircle at high frequency illustrated in the spectra shows the charge-transfer resistance ( $R_{ct}$ ) of the samples, indicating the electrocatalytic activity for tri-iodide reduction.<sup>26,27</sup> The results show a significant effect on the internal resistance of the solar cell, and consequently can affect the fill factor (FF) and conversion efficiency. The results show a very good consistency with

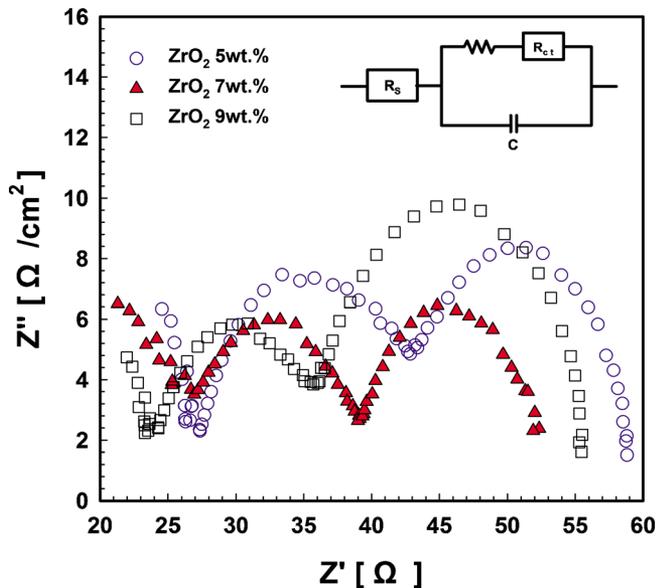


FIG. 2. (Color online) The Nyquist plot of the impedance characteristics between  $Z_{re}$  and  $Z_{im}$  with the angular frequency ( $\omega=2\pi f$ ) of the 5, 7, and 9 wt % of ZrO<sub>2</sub> nanofiber-doped photoelectrode.

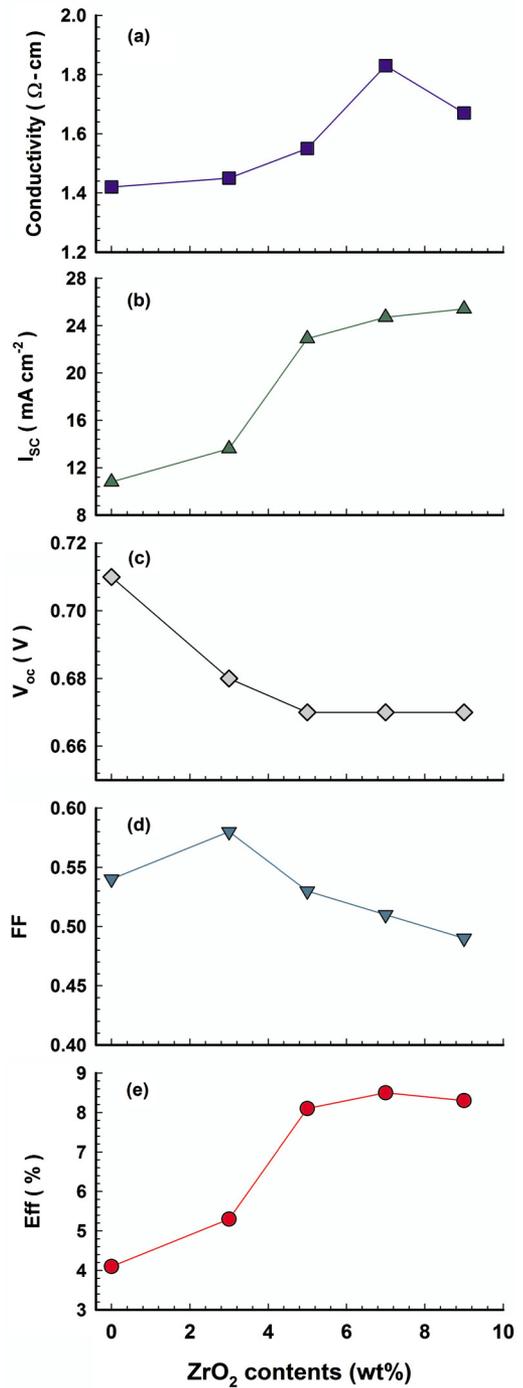


FIG. 3. (Color online) The values of conductivities (a) and photovoltage properties of the ZrO<sub>2</sub> nanofiber-doped dye-sensitized solar cells; short circuit current (b), open circuit voltage (c), FF (d), and efficiency (e).

conductivity, resistances, and cyclic voltammetry (CV) observations.

The bulk resistance ( $R_s$ ) of the 5 wt %, 7 wt %, and 9 wt % ZrO<sub>2</sub> doped TiO<sub>2</sub> electrodes are  $22.97 \times 10^{-3} \Omega$ ,  $24.52 \times 10^{-3} \Omega$ , and  $23.45 \times 10^{-3} \Omega$ , respectively. The charge transfer resistance ( $R_{ct}$ ) of the 5 wt %, 7 wt %, and 9 wt % devices are  $13.15 \times 10^{-3} \Omega$ ,  $7.58 \times 10^{-3} \Omega$ , and  $12.96 \times 10^{-3} \Omega$ , respectively. The  $R_{ct}$  represent mainly by the distance between the counter-electrode and photoelectrode, as well as, the effective area of the electrode. The  $R_s$  and  $R_{ct}$  could refer the adhesion properties between the substrate and Pt particles. Finally, the ZrO<sub>2</sub> nanofiber doped sys-

tem showed improvement of charge transferring property. The surface and/or interface of the cell is an important factor for charge transport of the short circuit current and life time of electron in the open circuit voltage.

The conductivity and resistance were measured using a four point probe measuring system (Chang min CMT-series) and resulted were averaged after seven times repetition for same condition. Figure 3(a) gives the values of conductivities: pristine ( $1.42 \times 10^{-9} \Omega\text{-cm}$ ), 3 wt % doped ( $1.45 \times 10^{-9} \Omega\text{-cm}$ ), 5 wt % doped ( $1.55 \times 10^{-9} \Omega\text{-cm}$ ), 7 wt % doped ( $1.83 \times 10^{-9} \Omega\text{-cm}$ ), and 9 wt % doped ( $1.67 \times 10^{-9} \Omega\text{-cm}$ ). The 7 wt % of  $\text{ZrO}_2$  nanofiber-doped sample shows the lowest resistance and highest conductivity.

The photocurrent-voltage properties of the devices obtained with the standard measurement condition. The photoelectric effects are shown from Figs. 3(b)–3(e). The best efficiency came from 7 wt %  $\text{ZrO}_2$  nanofibers doped device; with a short circuit current density ( $J_{sc}$ ) of  $24.7 \text{ mA/cm}^2$ , an open circuit voltage ( $V_{oc}$ ) of 0.67 V, a FF of 51% and an overall power conversion efficiency ( $\eta_{eff}$ ) of 8.3%. The efficiencies of pristine and doped samples (0 wt %, 3 wt %, 5 wt %, and 9 wt %) were 4.1%, 5.3%, 8.1%, and 8.3%, respectively. The increased value of  $I_{sc}$  from  $10.8 \text{ mAcm}^{-2}$  to  $24.7 \text{ mAcm}^{-2}$  and the value of  $V_{oc}$  0.67V make poor fill factor (0.52).

The FF marked the best with 3 wt % of the  $\text{ZrO}_2$  nanofibers doped device, and then gradually dropped. The open circuit voltage was hardly altered by the insertion of  $\text{ZrO}_2$  nanofibers. But, the short circuit currents were increased from 10.8 to 25.4 mA with the proportional to the concentration  $\text{ZrO}_2$  nanofibers. This suggests that the insertion of  $\text{ZrO}_2$  nanofibers gives (1) optimal electron pass way by reducing the surface and/or interface resistance, (2) porosity, which made by  $\text{ZrO}_2$  nanofibers, it gives many absorption site to the dye. The optimal porosity of the concentration of  $\text{ZrO}_2$  could be achieved with 7 wt %, which is close relating to the conductivity data, FF, and  $\eta_{eff}$ .

In conclusion,  $\text{ZrO}_2$  nanofibers were introduced into the photoelectrode of a dye sensitized solar cell. 204% enhanced efficiency was achieved to the concentration 7 wt %  $\text{ZrO}_2$  nanofibers. Doped  $\text{ZrO}_2$  nanofibers had contributed toward (1) redshift and much enhancement of the absorption spectra from UV to near infrared region just like tandem cell structure, (2) reduction in the resistance of the surface and/or interface of the photoelectrode, and (3) porosity, which made

by  $\text{ZrO}_2$  nanofibers, it gives many absorption site to the dye. The internal resistance of the photoelectrode is one of the important factor that affects the power conversion efficiency directly.  $\text{ZrO}_2$  nanofibers could play an important role in the realization of high efficiency dye-sensitized solar cells.

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